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Docket No.: 2336-255

PATENT

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Seung Wan CHAE

Confirmation No. 2799

U.S. Patent Application No. 10/812,015

Group Art Unit: 2811

Filed: March 30, 2004

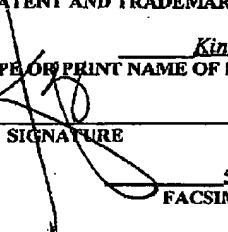
Examiner: Hung K Vu

For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE  
AND METHOD FOR MANUFACTURING THE SAMEAMENDMENTCOMMISSIONER FOR PATENTS  
P.O. Box 1450  
Alexandria VA 22313-1450

Sir:

The following amendments and remarks are submitted in response to the Official Action  
 dated *August 25, 2005*.

CERTIFICATION OF FACSIMILE TRANSMISSION  
 I HEREBY CERTIFY THAT THIS PAPER IS BEING FACSIMILE TRANSMITTED  
 TO THE PATENT AND TRADEMARK OFFICE ON THE DATE SHOWN BELOW

<i>Kindra Bryant</i>	TYPE OR PRINT NAME OF PERSON SIGNING CERTIFICATION
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571-273-8300	
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